$$we_{i}$$
know,  
 $I_{B}=I_{S}e^{\frac{V_{D}}{NV_{T}}}$ 
 $=0.0261 \text{ V}$ 

$$I_{S}=1.173\times10^{-15} \text{ A}$$

$$::I_{S}=1.173\times10^{-15} \text{ A}$$

(b) Fnom (a),  

$$Is = 1.173 \times 10^{-15} A$$
  
 $V_p = 0.76 V$   
 $T = 343K = 70^{\circ}C$ 

$$Y = \frac{KT}{V}$$
=  $(1.38\times16^{-23})_{1.6\times10^{-19}}$ 
=  $0.6296V$ 

$$V_{+} = \frac{KT}{9}$$

$$= \frac{(138\times10^{-23})\times303}{1.6\times10^{-19}}$$

$$= 0.0261 \text{ V}$$

 $30^{\circ}C \rightarrow 15 = 1.173 \times 10^{-15}A$   $40^{\circ}C \rightarrow 15 = 2.346 \times 10^{-15}A$   $50^{\circ}C \rightarrow 15 = 4.692 \times 10^{-15}A$   $60^{\circ}C \rightarrow 15 = 9.384 \times 10^{-15}A$  $70^{\circ}C \rightarrow 15 = 1.877 \times 10^{-14}A$ 

V 31.0 : 01

MAY XINV

$$I_D = I_S e^{\frac{V_D}{NV_T}}$$
  
=  $(1.877 \times 10^{-14}) \times e^{\frac{0.76}{1\times0.006}}$   
= 2.694 × 10<sup>-3</sup> A  
= 2.694 mA

$$V_{ON} = 0.75 + (2.5 \times 16^{-3} \times 26)$$

$$= 0.8 \, \text{V}$$

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(B) mond (a)

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V=150.0

NO HO WY

case	Va	Vb	Biasing type	ON OFF LOWIN
1	10	5	Forcuared	ON
2	5	10	Reverse	Breakdown
3	-5	2	Reverse	Breakdown
4	1-3	-5	Forewared	OFF

$$V_{T} = \frac{KT}{4}$$

$$= (1.38 \times 10^{-13}) \times 298$$

$$= (1.6 \times 10^{-19})$$

(c) 
$$V_{ON} = 2.1 V$$
  
 $IS = 10 nA$  when,  $T = 25°C$ 

Y' A CARLON

$$V_{ON} = 2.1 - (50 \times 2.5 \times 10^{-3})$$

$$= 1.975 \text{ V}$$

1.5.

1. 12 1 20.8

frex in

(a)

(i): current flow through P>n
...it is foreward biasing

(ii) 
$$1_D = 1_{MA} = 1_{X10^{-3}} A$$
  
 $V_D = 1_V$   
 $1_{S=10^{-4} NA} = 10^{-73} A$   
Let,  $V_T = x_V$ 

we know,

$$\frac{1}{x} = 23.026$$

Lavis 1 VI

V. n. V. de av (ii)

Freedon, (2000) => 
$$V_{1}=0.0434$$
 $K=1.38\times10^{-23}$  JK-1

 $V_{2}=1.6\times10^{-19}$  C

 $V_{3}=1.6\times10^{-19}$  C

$$T = 503.53 \text{ K}$$
  
= 230.53° c

(iv) 
$$I_{s} = 10^{-4} \text{ nA}$$
  
reducing  $10^{\circ}\text{ C}$ ,  $I_{s} = 5 \times 10^{-5} \text{ nA}$   
 $10^{\circ}\text{ C}$ ,  $I_{s} = 2.5 \times 10^{-5} \text{ nA}$ 

(b) (i)  

$$V_D=1$$
 V,  $V_{bn}=5$  V,  $V_{on}=2$  V  
Reverse biasing  
 $|V_D| \leq |V_{bn}|$ 

(ii) 
$$V_D = -1$$
,  $V_{bn} = 5V$ ,  $V_{on} = 2$   
Foreward biasing

$$V_D = 10^{V}$$

$$V_D < V_{ON}$$

$$I_D = 0^{A}$$

(iii) 
$$V_D=10V$$
,  $V_{bn}=5V$ ,  $V_{on}=2V$ 

Reverse bioring

ND> Von

ID = or

Foreward biasing

Vp=104

morrow thing of the armost as who we proved VD> VON

$$I_{D} = I_{S} e^{\frac{V_{D}}{V_{N}V_{T}}}$$

J. HIV

1 WIV

11:1 (c) has

tempercature will be soce

(b) Yes, tempercature affect the terrinon (cultin) putential of diodes. If we increase tempercature, turn-on voltage will decrease. On the other hand, if we decrease temperature turn-on voltage will increase

TI VON I

(c) 
$$I_{S}=6nA$$
  
 $n=1$   
 $V_{ON}=0.2V$   
 $|V_{bn}|=3V$   
 $T=35^{\circ}e=308K$ 

$$V_{T} = \frac{kT}{9}$$

$$= \frac{(1.38 \times 10^{-23}) \times 309}{1.6 \times 10^{-10}}$$

$$= 0.0265$$

Foreward biasing

$$\Rightarrow \frac{V_D}{0.0265} = 13.633$$

NO>VON

$$(ii) I_{p} = 0 mA \quad (p > n)$$

Foreward biasing

Reverse biasing

1. 6 11 11 11 11 11 11

21.3.12

100

From the greath
$$I_D = 20 \text{ mA} = 20 \times 10^{-3} \text{ A}$$

$$V_D = 0.8 \text{ V}$$

$$I_S = 1 \text{ pA} = 1 \times 10^{-12} \text{ A}$$

$$N = 1$$

/Tx = ?

we know,

Villagar or

(11:1) (11)

print of the same

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L. V. L.V.

$$4x = \frac{KTx}{9}$$
 $\Rightarrow 0.0337 = \frac{(1.38 \times 10^{-23}) \times 7x}{1.6 \times 10^{-19}}$ 

(c) As, et is a silicon diode, traver on voltage of silicon diode is 0.7 V

(d) from (b)
$$7x = 391 K$$

$$= 118°C$$

increasing loc,

$$V_{ON} = 0.7 - (10 \times 2.5 \times 10^{-3})$$

$$= 0.675$$

